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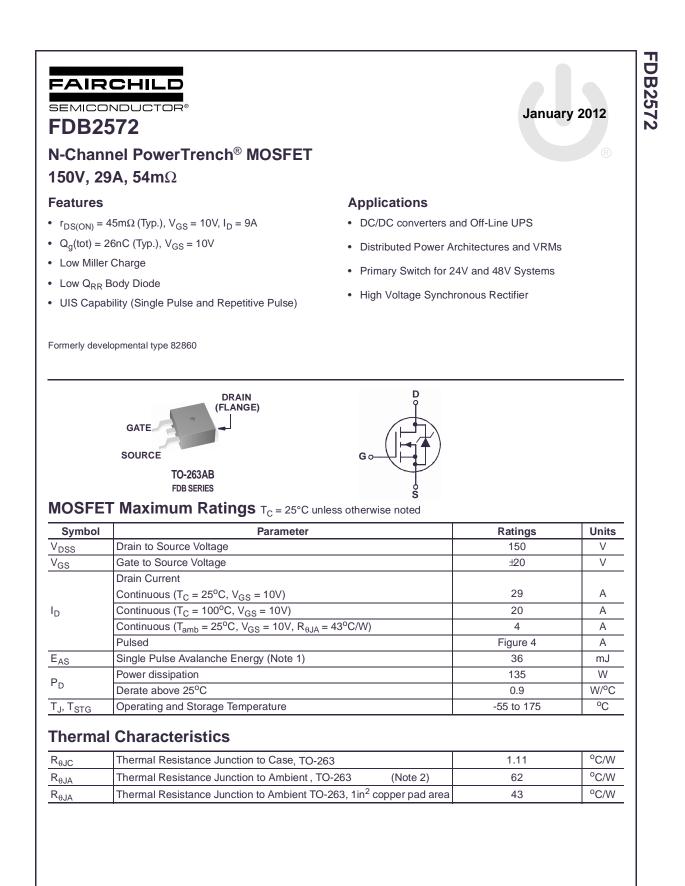


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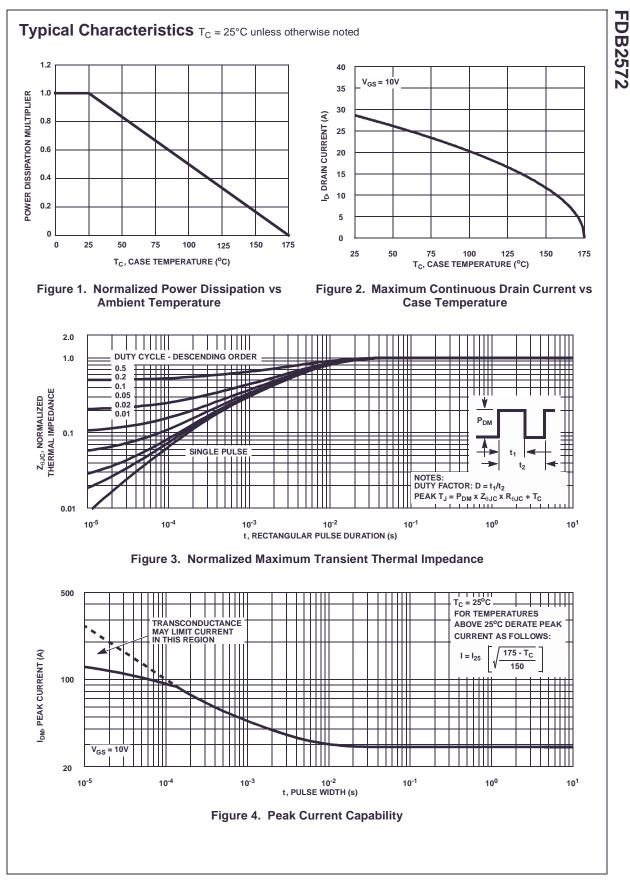
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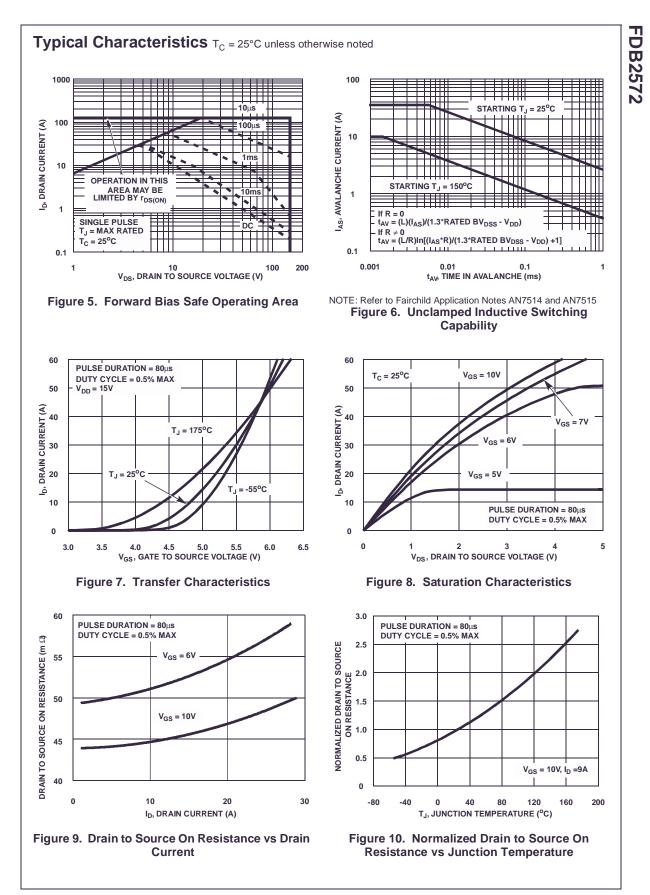


FDB2	larking	Device	Package	Reel Size	Таре	Width	Quantity	
FDB2572		FDB2572	TO-263AB 330mm		24mm		800 units	
Electrica	al Chara	acteristics T _C = 25	°C unless otherwi	se noted				
Symbol	Parameter		Test	Test Conditions		Тур	Max	Units
Off Chara	cteristics	5						
B _{VDSS}	1		- I _D - 250µA	$V_{00} = 0V$	150	-	-	V
20088	Drain to Source Breakdown Voltage Zero Gate Voltage Drain Current Gate to Source Leakage Current			$I_D = 250\mu A, V_{GS} = 0V$ $V_{DS} = 120V$		-	1	v
DSS			$V_{GS} = 0V$	$T_{\rm C} = 150^{\rm o}$	-	-	250	μA
GSS			V _{GS} = ±20\			-	±100	nA
			00			1		
)n Chara	cteristics	3						
√ _{GS(TH)}	Gate to Se	ource Threshold Voltage		, I _D = 250μA	2	-	4	V
	Drain to Source On Resistance		I _D =9A, V _{GS}		-	0.045	0.054	
DS(ON)				4A, V _{GS} = 6V, -		0.050	0.075	Ω
			I _D =9A, V _{GS}	=10V, T _C =175°C	-	- 0.126 0.14		
Dynamic	Characte	ristics						
-	Input Cap				-	1770	-	pF
	Output Cap		V _{DS} = 25V	, V _{GS} = 0V,	-	183	-	pr pF
C _{OSS}		ransfer Capacitance	f = 1MHz			40	-	pF pF
C _{RSS}			$\lambda = 0 \lambda t$	o 10\/	-	40 26	- 34	nC
Q _{g(TOT)}	-	Charge at 10V	$V_{GS} = 0V t$		-	3.3	4.3	nC
⊋ _{g(TH)}	-	Gate Charge	$V_{GS} = 0V t$	$V_{DD} = 75V$ $I_D = 9A$	-	3.3 8	4.3	nC
ב _{gs} ב	_	rge Threshold to Plateau		$I_{g} = 9A$ $I_{g} = 1.0mA$		5	-	nC
Q _{gs2}		rain "Miller" Charge		.g	-	6	-	nC
Q _{gd}	Calc to D	an which onarge				0		110
Resistive	Switchin	g Characteristics	(V _{GS} = 10V)					
t _{ON}	Turn-On T	ïme			-	-	36	ns
t _{d(ON)}	Turn-On D	elay Time			-	11	-	ns
t _r	Rise Time	}	V _{DD} = 75V,	I _D = 9A	-	14	-	ns
	Turn-Off D	elay Time		, R _{GS} = 11.0Ω	-	31	-	ns
	Fall Time				-	14	-	ns
t _{d(OFF)}				-		-	66	ns
t _{d(OFF)}	Turn-Off T	ïme			1		÷	
t _{d(OFF)} t _f t _{OFF}		-			1			
t _{d(OFF)} t _f t _{OFF}		ime le Characteristics			ı		1.05	1/
t _{d(OFF)} t _f tOFF Drain-Sou	Irce Diod	-	$I_{SD} = 9A$		-	-	1.25	V
t _{d(OFF)} t _f tOFF Drain-Sou V _{SD}	Source to	le Characteristics Drain Diode Voltage	$I_{SD} = 4A$	L /dt =100 4/42	-	-	1.0	V
i _{d(OFF)} i _f ioff Drain-Sou	Source to	e Characteristics	I _{SD} = 4A I _{SD} = 9A, d	I _{SD} /dt =100A/μs I _{SD} /dt =100A/μs	-	-		

FDB2572

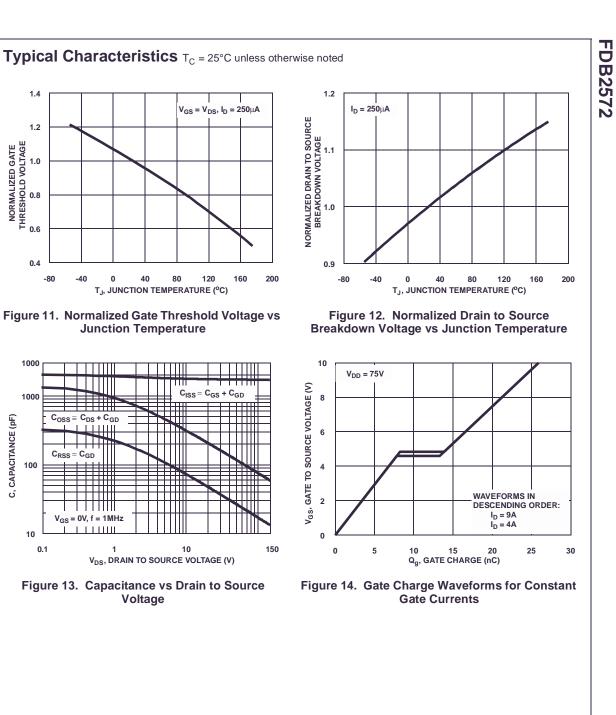


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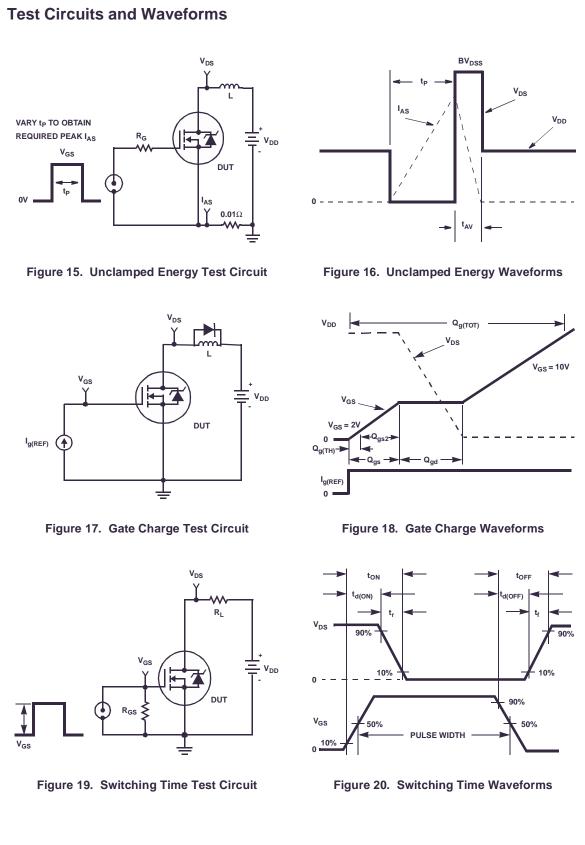
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FDB2572 Rev. C



FDB2572 Rev. C





FDB2572

Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta,JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

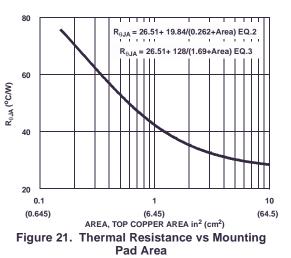
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeter square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

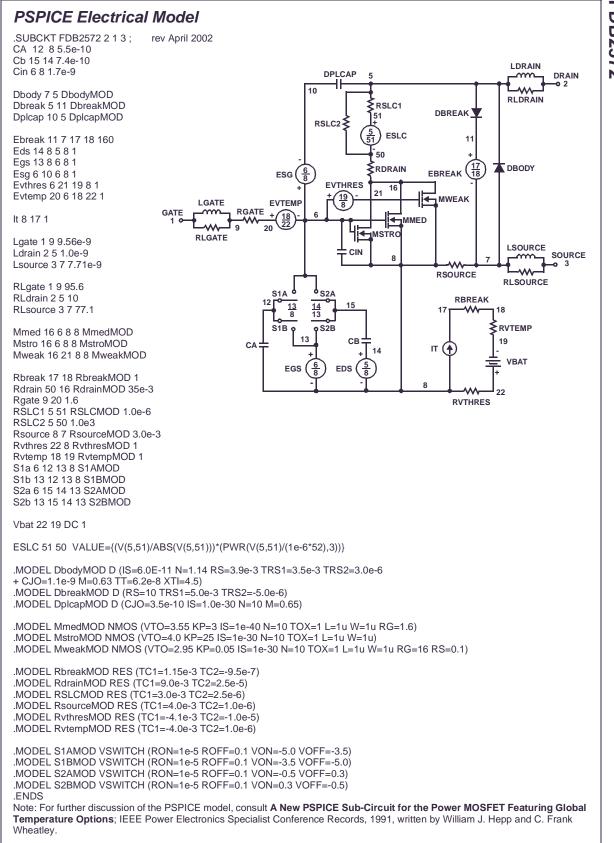
Area in Inches Squared

$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
(EQ. 3)

Area in Centimeters Squared



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DRAIN

SOURCE

o 3

• 2

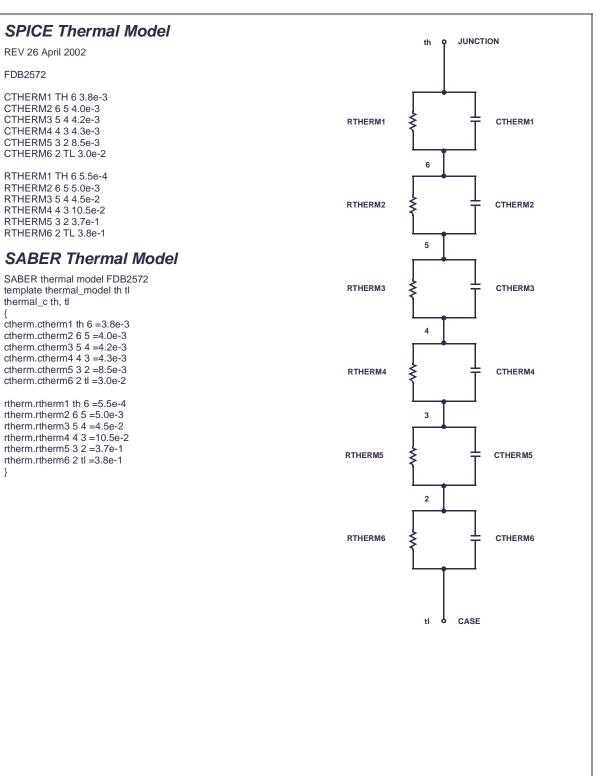
var i iscl dp..model dbodymod = (isl=6.0e-11,nl=1.14,rs=3.9e-3,trs1=3.5e-3,trs2=3.0e-6,cjo=1.1e-9,m=0.63,tt=6.2e-8,xti=4.5) dp..model dbreakmod = (rs=10.trs1=5.0e-3.trs2=-5.0e-6)dp..model dplcapmod = (cjo=3.5e-10,isl=10.0e-30,nl=10,m=0.65) m..model mmedmod = (type=_n,vto=3.55,kp=3,is=1e-40, tox=1) m..model mstrongmod = (type=_n,vto=4.0,kp=25,is=1e-30, tox=1) m.model mstrongmod = (type=_11,vto=4.0, kp=2.05, ks=10.00, tox=1, rs=0.1) m.model mweakmod = (type=_n,vto=2.95, kp=0.05, is=1e-30, tox=1, rs=0.1) LDRAIN sw_vcsp..model s1amod = (ron=1e-5,roff=0.1,von=-5.0,voff=-3.5) sw_vcsp..model s1bmod = (ron=1e-5,roff=0.1,von=-3.5,voff=-5.0) \mathbf{w} sw_vcsp..model s2amod = (ron=1e-5,roff=0.1,von=-0.5,voff=0.3) RLDRAIN **₹**RSLC1 sw_vcsp..model s2bmod = (ron=1e-5,roff=0.1,von=0.3,voff=-0.5) 51 c.ca n12 n8 = 5.5e-10RSLC2 ≥ c.cb n15 n14 = 7.4e-10 Ŧ ISCL c.cin n6 n8 = 1.7e-9DBREAK 50 dp.dbody n7 n5 = model=dbodymod **₹**rdrain <u>6</u> 8 ESG 11 dp.dbreak n5 n11 = model=dbreakmod DBODY EVTHRES 16 dp.dplcap n10 n5 = model=dplcapmod 21 $\frac{19}{8}$. **MWEAK** EVTEMP LGATE spe.ebreak n11 n7 n17 n18 = 160 GATE RGATE 18 22 EBREAK . spe.eds n14 n8 n5 n8 = 1 9 20 ~~~ spe.egs n13 n8 n6 n8 = 1 RLGATE spe.esg n6 n10 n6 n8 = 1 LSOURCE CIN spe.evthres n6 n21 n19 n8 = 1 я spe.evtemp n20 n6 n18 n22 = 1 RSOURCE RLSOURCE i.it n8 n17 = 1 RBREAK 13 <u>14</u> 13 15 17 18 \sim l.lgate n1 n9 = 9.56e-9 I.ldrain n2 n5 = 1.0e-9 RVTEMP S1B S2B l.lsource n3 n7 = 7.71e-9 CB 19 CA IT (14 res.rlgate n1 n9 = 95.6 VBAT 6 5 EGS EDS res.rldrain n2 n5 = 10 res.rlsource n3 n7 = 77.1 8 22 RVTHRES m.mmed n16 n6 n8 n8 = model=mmedmod, l=1u, w=1u m.mstrong n16 n6 n8 n8 = model=mstrongmod, l=1u, w=1u m.mweak n16 n21 n8 n8 = model=mweakmod, l=1u, w=1u res.rbreak n17 n18 = 1, tc1=1.15e-3,tc2=-9.5e-7 res.rdrain n50 n16 = 35e-3, tc1=9.0e-3,tc2=2.5e-5 res.rgate n9 n20 = 1.6res.rslc1 n5 n51 = 1.0e-6, tc1=3.0e-3,tc2=2.5e-6 res.rslc2 n5 n50 = 1.0e3 res.rsource n8 n7 = 3.0e-3, tc1=4.0e-3,tc2=1.0e-6 res.rvthres n22 n8 = 1, tc1=-4.1e-3,tc2=-1.0e-5 res.rvtemp n18 n19 = 1, tc1=-4.0e-3,tc2=1.0e-6 sw vcsp.s1a n6 n12 n13 n8 = model=s1amod sw_vcsp.s1b n13 n12 n13 n8 = model=s1bmod sw_vcsp.s2a n6 n15 n14 n13 = model=s2amod sw_vcsp.s2b n13 n15 n14 n13 = model=s2bmod v.vbat n22 n19 = dc=1 equations { i (n51->n50) +=iscl iscl: v(n51,n50) = ((v(n5,n51)/(1e-9+abs(v(n5,n51))))*((abs(v(n5,n51)*1e6/52))** 3))} }

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SABER Electrical Model

REV April 2002

ttemplate FDB2572 n2,n1,n3 electrical n2,n1,n3





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Rev. 161

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